Sample Question Paper – I

9034

Course Name :- Electronics Engineering group

Course code :- EE/EP/ET/EJ/EN/EX/IE/IS/IC/DE/MU/IU/ED/EI

Semester :- Third

Subject :- Basic Electronics

Duration :- 3 hours Marks: 80

Instructions:

1. All questions are compulsory

- 2. Illustrate your answers with neat sketches wherever necessary
- 3. Figures to the right indicate full marks
- 4. Assume suitable data if necessary
- 5. Preferably, write the answers in sequential order

Q. No. 1 Attempt Any EIGHT of the following

Marks 16

- a. State the minority and majority carriers in N type and P type semiconductors.
- b. What is the meaning of term rectification? State its need.
- c. Draw constructional diagram for N channel JFET.
- d. State the need for biasing a transistor when used as an amplifier.
- e. Define load and line regulation with respect to regulator.
- f. Draw CB and CC configuration of BJT. List one application of CB and CC amplifier.
- g. State operating principle of LED.
- h. Which filter is practically preferred to get pure DC output? Draw the circuit diagram of the same.
- i. Why an ordinary junction transistor is called a bipolar device?
- j. State the meaning of small signal amplifier. List two applications of it.

Q. No. 2 Attempt Any THREE of the following

Marks 12

- a. For a PN junction diode, applied voltages are 0V, +5V, -10V. Draw the PN junction indicating relative width of depletion region in each case.
- b. Define the terms Static and Dynamic resistance of diode. What will be static resistance of the diode operated at 0.67 V and 2m
- c. Compare centre tap and bridge rectifier on the basis of
 - 1. TUF 2. PIV
- 3. No. of diodes
- 4. Ripple frequency
- d. Give four important features of IC723. What is the use of C_L & C_S terminals?

Q. No. 3 Attempt Any THREE of the following

Marks 12

- a. With respect to JFET define:
 - 1. Drain resistance 2. Transconductance 3. Amplification factor.
 - 4. Give mathematical relation between them.
- b. Derive the relation between α and β with respect to BJT.
- c. What is meaning of the term heat sink? What is the significance of its physical structure? Draw a neat sketch of typical heat sink.
- d. Draw two stage R-C coupled amplifier. Draw its frequency response.

Q. No. 4 Attempt Any FOUR of the following

Marks 16

- a. Explain on the basis of operating principle, how LED is different from an ordinary PN junction diode?
- b. Draw circuit diagram of Half wave rectifier with capacitor filter. What is the peak inverse voltage across the diode with and without capacitor connected?
- c. Compare CB and CE configuration on the basis of -
 - 1. Input dynamic resistance 2. Output dynamic resistance. 3. Current gain 4. Leakage current
- d. Draw the diagram for emitter bias method for BJT. Describe its operation.
- e. Why different stages of amplifier are cascaded? State different methods used for cascading.
- f. (i) Give units of h_{ie} , h_{fe} , h_{oe} , h_{re} .
 - (ii) Draw the pin diagram of IC723.

Q. No. 5 Attempt Any THREE of the following

Marks 12

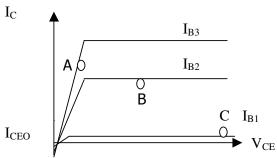
- a. Construct a dual power supply capable of giving ±15V using 78xx and 79xx series ICs.
- b. Draw the circuit diagram of CB amplifier. Give its one application.
- c. For a given CE amplifier, output voltage $V_o = 2V$, input voltage $V_{in} = 20 \text{mV}$ find out its gain in dB. Calculate half power point.
- d. Draw experimental set up to obtain diode characteristics. State function of each element in set up.

Q. No. 6 Attempt Any THREE of the following

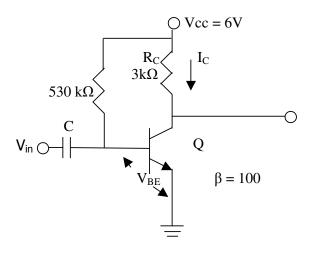
Marks 12

- a. Compare CC and CE amplifier on the basis of
 - i). Input impedance ii). Current gain iii). Power gain iv). Input output phase relation.
- b. A π filter with FWR has C1 = C2 = 50 μ f and L = 5H. The load current is 0.250 μ A at 50V DC.
- c. Find the ripple factor.

d. Identify the following characteristics. State in which region transistor is operated at point A, B and C.



e. Study the following fixed bias circuit.



Draw the D.C. load line & determine the operating point.